

isc N-Channel MOSFET Transistor

AOTF404

FEATURES

- Drain Current –I_D= 26A@ T_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-: V_{DSS}= 105V(Min)
- Static Drain-Source On-Resistance
- : $R_{DS(on)}$ = 28m Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

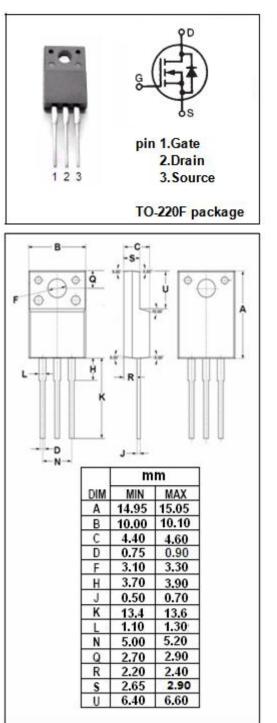
• Designed for use in switch mode power supplies and general purpose applications.

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	105	V	
V_{GS}	Gate-Source Voltage-Continuous	±25	v	
ID	Drain Current-Continuous	26	А	
I _{DM}	Drain Current-Single Pluse	910	А	
P _D	Total Dissipation @T _c =25°C 43		w	
TJ	Max. Operating Junction Temperature	ax. Operating Junction Temperature -55~175		
T _{stg}	Storage Temperature -55~175		°C	

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
R _{th j-c}	Thermal Resistance, Junction to Case	3.5	°C/W	





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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	105			V
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} = 5V; I _D = 0.25mA	2.5		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 20A V _{GS} = 10V; I _D = 20A@T _J = 125℃			28 47	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±25V;V _{DS} = 0			±100	nA
IDSS	Zero Gate Voltage Drain Current	V _{DS} = 105V; V _{GS} = 0 V _{DS} = 105V; V _{GS} = 0@T _J = 55°C			1 5	μA
V _{SD}	Forward On-Voltage	I _S = 1A; V _{GS} = 0			1	V



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